

CORRECTION

[View Article Online](#)
[View Journal](#) | [View Issue](#)



Cite this: *J. Mater. Chem. C*, 2021, **9**, 2977

DOI: 10.1039/d1tc90031e

rsc.li/materials-c

Correction: Large-area printed low-voltage organic thin film transistors *via* minimal-solution bar-coating

Sujin Sung,^a Won-June Lee,^a Marcia M. Payne,^b John E. Anthony,^b Chang-Hyun Kim^{*c} and Myung-Han Yoon^{*a}

Correction for 'Large-area printed low-voltage organic thin film transistors *via* minimal-solution bar-coating' by Sujin Sung *et al.*, *J. Mater. Chem. C*, 2020, **8**, 15112–15118, DOI: 10.1039/D0TC03089A.

The authors wish to include an additional funding number in the Acknowledgements section of this article. The corrected Acknowledgements section should read as follows (the new funding number is shown in bold type):

This work was supported by the National Research Foundation (NRF) grant funded by the Korea government (MSIT) (NRF-2018M3A7B4070988, NRF-2020M3D1A1030660, NRF-2020M3D1A1069831, **NRF-2020M1A2A2080748**) and, by GIST Research Institute (GRI) grant funded by the GIST in 2020.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

^a School of Materials Science and Engineering, Gwangju Institute of Science and Technology, Gwangju 61005, Republic of Korea. E-mail: mhyoon@gist.ac.kr

^b Department of Chemistry, University of Kentucky, Lexington, Kentucky 40506, USA

^c Department of Electronic Engineering, Gachon University, Seongnam 13120, Republic of Korea. E-mail: chang-hyun.kim@gachon.ac.kr

